

Dual Schottky Barrier Diode

MMBD352WT1G, NSVMMBD352WT1G

These devices are designed primarily for UHF mixer applications but are suitable also for use in detector and ultra-fast switching circuits.

Features

- Very Low Capacitance Less Than 1.0 pF @ 0 V
- Low Forward Voltage 0.5 V (Typ) @ $I_F = 10 \text{ mA}$
- AEC Qualified and PPAP Capable
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Symbol	ymbol Rating		Unit
V_{R}	Continuous Reverse Voltage	7.0	V_{CC}

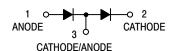
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Symbol	Characteristic	Max	Unit
P _D	Total Device Dissipation FR-5 Board (Note 1) T _A = 25°C Derate above 25°C	200 1.6	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	625	°C/W
P _D	Total Device Dissipation Alumina Substrate (Note 2) T _A = 25°C Derate above 25°C	300 2.4	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	417	°C/W
T _J , T _{stg}	Junction and Storage Temperature	-55 to +150	°C

- 1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.





MARKING DIAGRAM



M5 = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBD352WT1G	SOT-323 (Pb-Free)	3,000 / Tape & Reel
NSVMMBD352WT1G	SOT-323 (Pb-Free)	3,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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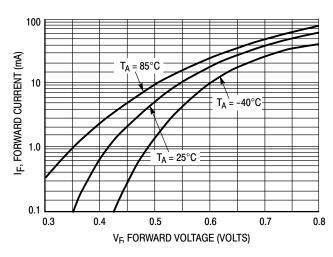
^{*}For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, <u>SOLDERRM/D</u>.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Characteristic	Min	Max	Unit			
OFF CHAI	OFF CHARACTERISTICS						
V _F	Forward Voltage (I _F = 10 mAdc)	-	0.60	V			
I _R	Reverse Voltage Leakage Current (V _R = 3.0 V) (V _R = 7.0 V)	- -	0.25 10	μΑ			
С	Capacitance (V _R = 0 V, f = 1.0 MHz)	-	1.0	pF			

TYPICAL CHARACTERISTICS



1.0 0.9 0.8 0.7 0.6 0 1.0 2.0 3.0 4.0 V_B, REVERSE VOLTAGE (VOLTS)

Figure 1. Forward Voltage

Figure 2. Capacitance







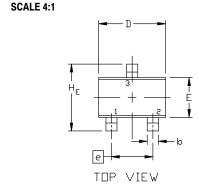
SC-70 (SOT-323) CASE 419 ISSUE R

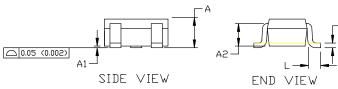
DATE 11 OCT 2022

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH

	MILLIMETERS			INCHES			
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.	
Α	0.80	0.90	1.00	0.032	0.035	0.040	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A2		0.70 REF			0.028 BSC		
b	0.30	0.35	0.40	0.012	0.014	0.016	
С	0.10	0.18	0.25	0.004	0.007	0.010	
D	1.80	2.00	2.20	0.071	0.080	0.087	
E	1.15	1.24	1.35	0.045	0.049	0.053	
е	1.20	1.30	1.40	0.047	0.051	0.055	
e1	0.65 BSC				0.026 BS	C	
L	0.20	0.38	0.56	0.008	0.015	0.022	
HE	2.00	2.10	2.40	0.079	0.083	0.095	





GENERIC MARKING DIAGRAM

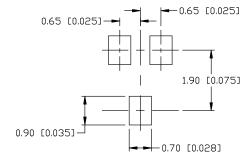


XX = Specific Device Code

M = Date Code

■ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



For additional information on our Pb-Free strategy and soldering details, please download the ID Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

SOLDERING FOOTPRINT

STYLE 1: CANCELLED	STYLE 2: PIN 1. ANODE 2. N.C. 3. CATHODE	STYLE 3: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. CATHODE	
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	STYLE 10:	STYLE 11:
PIN 1. EMITTER	PIN 1. BASE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. CATHODE
2. BASE	2. EMITTER	2. SOURCE	2. CATHODE	2. ANODE	CATHODE
COLLECTOR	COLLECTOR	3. DRAIN	CATHODE-ANODE	3. ANODE-CATHODE	CATHODE

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DESCRIPTION:	SC-70 (SOT-323)		PAGE 1 OF 1

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